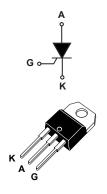


TN3015H-6I

Datasheet

High temperature 30 A, 600 V TO220 insulated thyristor SCRs



TO-220AB insulated

Features

- High junction temperature: T_j = 150 °C
- High noise immunity dV/dt = 1000 V/ μ s up to 150 °C
- Peak off-state voltage V_{DRM}/V_{RRM} = 600 V
- High turn-on current rise dl/dt = 100 A/µs
- ECOPACK2 compliant
- Insulated package TO-220AB:
 - Insulated voltage: 2500 V_{RMS}
 - Complies with UL 1557 (File ref : E81734)

Applications

- General purpose AC line load switching
- Motorbike voltage regulator circuits
- Inrush current limiting circuits
- Motor control circuits and starters
- Heating resistor control, Solid State Relays
- Lighting

Description

Thanks to its operating junction temperature up to 150°C, the TN3015H-6I offers high thermal performance operation up to 30 A rms.

Its trade-off noise immunity (dV/dt = 1000 V/ μ s) versus its gate triggering current (I_{GT} = 15 mA) and its turn-on current rise (dI/dt = 100 A/ μ s) allows to design robust and compact control circuit for voltage regulator in motorbikes and industrial drives, overvoltage crowbar protection, motor control circuits in power tools and kitchen appliances and inrush current limiting circuits.

Product status				
TN3015H-6I				
Product summary				
Order code TN3015H-6I				
Package	TO-220AB Ins.			
V _{DRM} /V _{RRM}	600 V			
Тј	150 °C			
I _{GT}	15 mA			

1 Characteristics

Symbol	Parameter	Value	Uni		
I _{T(RMS)}	RMS on-state current (180 ° conduction angle) $T_c = 96 °C$		T _c = 96 °C	30	Α
			T _c = 96 °C	19	
I _{T(AV)}	I _{T(AV)} Average on-state current (180 ° conduction angle)		T _c = 111 °C	15	A
1		T _c = 127 °C	10		
1	Non repetitive surge pools on state surrent (T	initial - 25 °C)	t _p = 8.3 ms	295	
I _{TSM}	Non repetitive surge peak on-state current (T	j miliai = 25°C)	t _p = 10 ms	270	A
l ² t	$I^{2}t$ value for fusing (T _j initial = 25 °C)		t _p = 10 ms	364	A ² s
dl/dt	$I_G = 2 \times I_{GT}, tr \le 100 \text{ ns}$	f = 60 =	T _i = 25 °C	100	A /
di/dt	Critical rate of rise of on-state current	rise of on-state current f = 60 Hz		100	A/µs
V _{DRM} /V _{RRM}	Repetitive peak off-state voltage			600	V
V _{DSM} /V _{RSM}	Non repetitive surge peak off-state voltage	t _p = 10 ms	T _j = 25 °C	V _{DRM} /V _{RRM} + 100	V
I _{GM}	Peak gate current	t _p = 20 μs	T _j = 150 °C	4	Α
P _{G(AV)}	Average gate power dissipation		T _j = 150 °C	1	W
V _{RGM}	Maximum peak reverse gate voltage		T _j = 25 °C	5	V
T _{stg}	Storage junction temperature range			-40 to +150	°C
Tj	Maximum operating junction temperature			-40 to +150	°C
ΤI	Maximum lead temperature soldering during 10 s			260	°C
V _{ins}	Insulation RMS voltage, 1 minute			2500	V

Table 1. Absolute maximum ratings (limiting values)

Table 2. Electrical characteristics (T_j = 25 °C unless otherwise specified)

Symbol	Test conditions			Value	Unit
lan			Min.	6	mA
I _{GT}	$V_{\rm D} = 12 \text{ V}, \text{ R}_{\rm L} = 33 \Omega$			15	IIIA
V _{GT}			Max.	1.3	V
V _{GD}	$V_{\rm D}$ = $V_{\rm DRM}$, $R_{\rm L}$ = 3.3 k Ω $T_{\rm j}$ = 150 °C			0.15	V
I _H	I _T = 500 mA, gate open Max.			60	mA
١L	I _G = 1.2 x I _{GT} Max.			75	mA
dV/dt	V_D = 402 V, gate open T_j = 150 °C			1000	V/µs
t _{gt}	$I_T = 60 \text{ A}, V_D = 600 \text{ V}, I_G = 100 \text{ mA}, (dI_G/dt) \text{ max} = 0.2 \text{ A}/\mu \text{s}$ Typ.			1.9	μs
tq	$I_T = 30 \text{ A}, \text{ V}_D = 402 \text{ V}, (\text{di/dt}) \text{off} = 30 \text{ A/} \mu \text{s}, \text{ V}_R = 25 \text{ V}, \text{ dV}_D/\text{dt} = 50 \text{ V/} \mu \text{s} \qquad T_j = 150 ^\circ \text{C} \qquad Typ$			80	μs

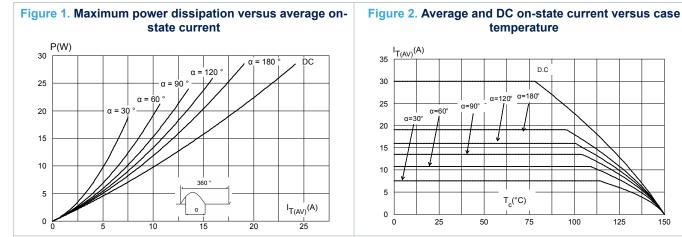
Table 3. Static characteristics

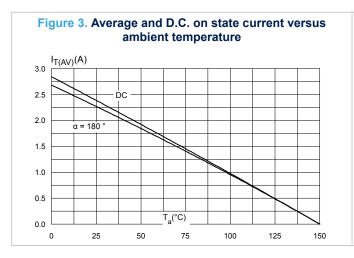
Symbol Test conditions				Value	Unit
V _{TM}	I _{TM} = 60 A, t _p = 380 μs	T _j = 25 °C	Max.	1.6	V
V _{TO}	Threshold voltage	T _j = 150 °C	Max.	0.84	v
R _D	Dynamic resistance	T _j = 150 °C	Max.	14	mΩ
I _{DRM} ,	$V_D = V_{DRM}, V_R = V_{RRM}$	T _j = 25 °C	Max.	10	μA
I _{RRM}	$v_D = v_{DRM}, v_R = v_{RRM}$	T _j = 150 °C	ividX.	5	mA

Table 4. Thermal parameters

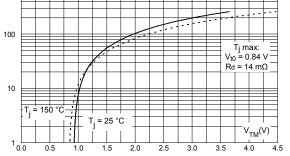
Symbol	Parameter			
R _{th(j-c)}	Junction to case	Max.	1.9	°C/W
R _{th(j-a)}	Junction to ambient	Тур.	60	C/VV

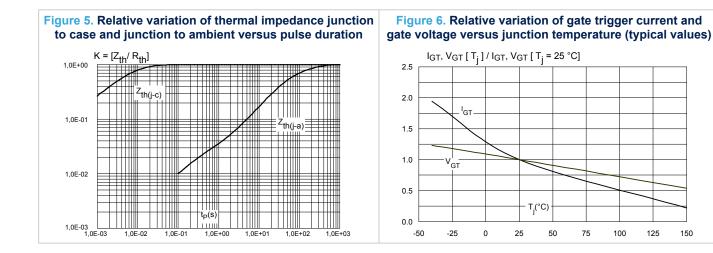
1.1 **Characteristics curves**





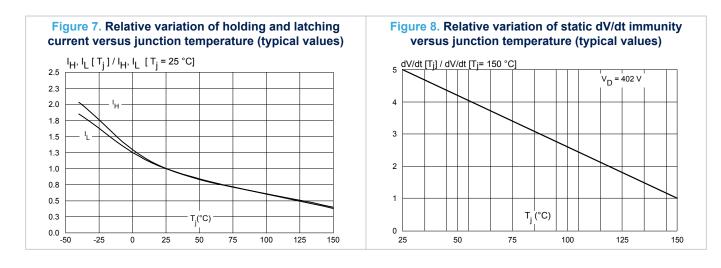
125 150 Figure 4. On-state characteristics (maximum values) I_{TM}(A) 1000 100

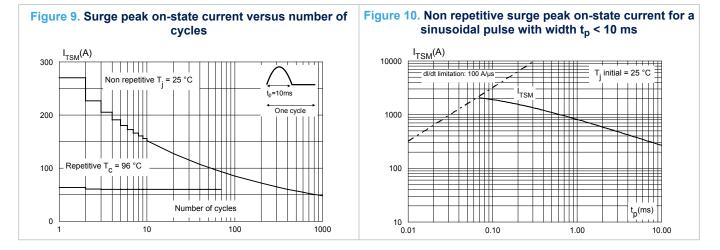




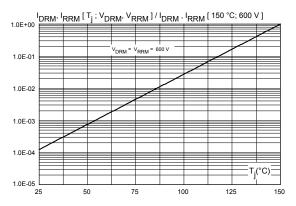
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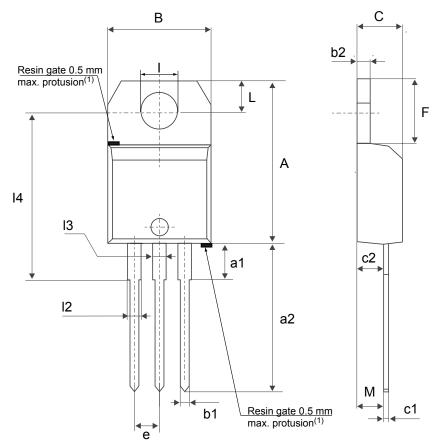
2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 TO-220AB insulated package information

- Molding compound resin is halogen-free and meets flammability standard UL94 level 0
- Lead-free package leads finishing
- ECOPACK2 compliant
- Recommended torque: 0.4 to 0.6 N.m

Figure 12. TO-220AB insulated package outline



(1)Resin gate position accepted in one of the two positions or in the symmetrical opposites.

	Dimensions					
Ref.		Millimeters			Inches ⁽¹⁾	
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	15.20		15.90	0.5984		0.6260
a1		3.75			0.1476	
a2	13.00		14.00	0.5118		0.5512
В	10.00		10.40	0.3937		0.4094
b1	0.61		0.88	0.0240		0.0346
b2	1.23		1.32	0.0484		0.0520
С	4.40		4.60	0.1732		0.1811
c1	0.49		0.70	0.0193		0.0276
c2	2.40		2.72	0.0945		0.1071
е	2.40		2.70	0.0945		0.1063
F	6.20		6.60	0.2441		0.2598
I	3.73		3.88	0.1469		0.1528
L	2.65		2.95	0.1043		0.1161
12	1.14		1.70	0.0449		0.0669
13	1.14		1.70	0.0449		0.0669
14	15.80	16.40	16.80	0.6220	0.6457	0.6614
М		2.6			0.1024	

Table 5. TO-220AB insulated package mechanical data

1. Inch dimensions are for reference only.

3 Ordering information

Figure 13. Ordering information scheme

Series TN = SCR RMS current 30 = 30 A	TN 30 15	H - 6 I
Gate triggering current 15=15 m A		
High temperature H = 150 °C		
Voltage 6 = 600 V		
Package I = TO-220AB insulated		
Delivery mode Blank = tube		

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
TN3015H-6I	TN3015H6I	TO-220AB ins.	2.3 g	50	Tube

Revision history

Table 7. Document revision history

Date	Revision	Changes
22-May-2019	1	Initial release.



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